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Vishay Semiconductors

# High Performance Schottky Rectifier, 2 x 20 A





Base common cathode 0 2 0 2 0 2 0 3 Anode cathode Anode

1 Common 3 Anode cathode Anode VS-43CTQ...S-M3

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VS-43CTQ...-1-M3

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 20 A					
V <sub>R</sub>	80 V, 100 V					
V <sub>F</sub> at I <sub>F</sub>	0.67 V					
I <sub>RM</sub> max.	11 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
E <sub>AS</sub>	7.50 mJ					
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES						
I <sub>F(AV)</sub>	Rectangular waveform	40	A					
V <sub>RRM</sub>		80/100	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	A					
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.67	V					
TJ	Range	-55 to +175	°C					

VOLTAGE RATINGS							
PARAMETER SYMBOL		VS-43CTQ080S-M3 VS-43CTQ080-1-M3	VS-43CTQ100S-M3 VS-43CTQ100-1-M3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	80	100	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	v				



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ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST COND	TEST CONDITIONS					
Maximum average	per leg				20				
forward current See fig. 5	per device	$I_{F(AV)}$ 50 % duty cycle at $T_C = 135$ °C, rectangular wavefo		, rectangular waveform	40	А			
	Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	850	~			
surge current per leg See fig. 7		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	275				
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH		7.50	mJ			
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim		0.50	А			

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
		20 A	T.I = 25 °C	0.81				
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	40 A	1j=25 0	0.98	V			
See fig. 1	VFM ()	20 A	T 125 °C	0.67				
		40 A	T <sub>J</sub> = 125 °C	0.81				
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1	mA			
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	11	ШA			
Threshold voltage	V <sub>F(TO)</sub>			0.71	V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$	0.43	mΩ				
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		1480	pF			
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body 8.0			nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000						

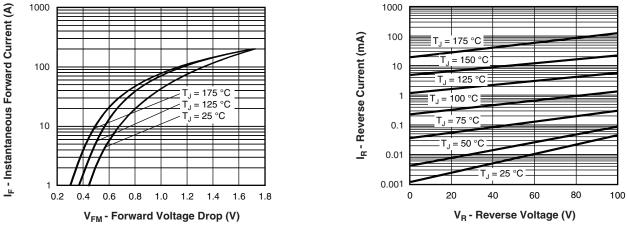
#### Note

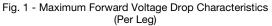
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

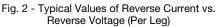
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage	je	T <sub>J</sub> , T <sub>Stg</sub>		-55 to 175	°C			
Maximum thermal resistance junction to case per leg	,	D	DC operation	2.0				
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>		1.0	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
			Cose at the D2DAK (TO 262AD)	43CTC	2080S			
	Marking device		Case style D <sup>2</sup> PAK (TO-263AB)	43CTC	Q100S			
warking device			Case style TO 26244	43CTQ080-1				
			Case style TO-262AA	43CTQ100-1				

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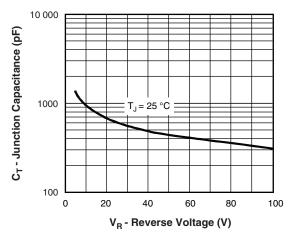
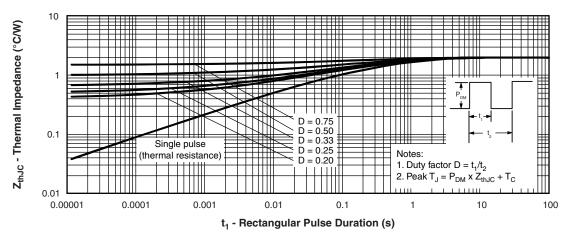


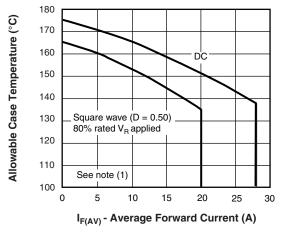
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

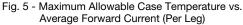




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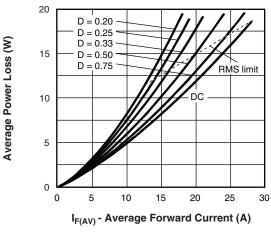


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

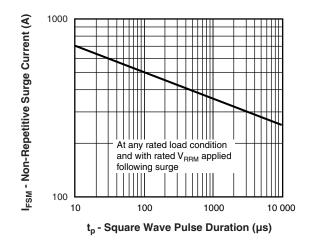


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

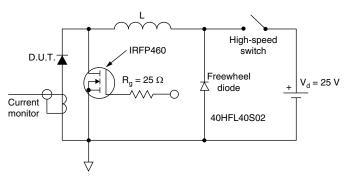


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \; \mathsf{power} \; \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \; \mathsf{x} \; \mathsf{V_{\mathsf{FM}}} \; \mathsf{at} \; (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \; (\mathsf{see} \; \mathsf{fig.} \; \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \; \mathsf{power} \; \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \; \mathsf{x} \; \mathsf{I}_{\mathsf{R}} \; (\mathsf{1-D}); \; \mathsf{I}_{\mathsf{R}} \; \mathsf{at} \; \mathsf{V}_{\mathsf{R1}} = \mathsf{10} \; \mathsf{V} \\ \end{array}$ 

Revision: 27-Oct-17

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### **ORDERING INFORMATION TABLE**

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VISHAY

Device code	VS-	43	С	т	Q	100	S	TRL	-МЗ
		(2)	(3)	(4)	(5)	(6)	$\overline{7}$	(8)	(9)
	<u> </u>		U		J	U		U	J
	1	- Visl	hay Serr	nicondu	ctors pr	oduct			
	2	- Cur	rent rati	ng (40 A	A)				
	3 -	- Circ	cuit con	figuratio	n: C = c	commor	n catho	de	
	4	• T=	TO-220	)					
	5	- Sch	nottky "O	Q" series	3				
	6	- Vol	tage rati	ngs —		080 = 100 =			
	7 -	• s	= D <sup>2</sup> PA	K (TO-2	63AB)	100 -			
		• -1	= TO-2	62AA					
	8 -	• N	one = tu	ıbe					
		• T	RL = tap	e and r	eel (left	oriented	d - for E	<sup>2</sup> PAK (1	TO-263
		• TI	RR = tap	be and r	eel (righ	t orient	ed - for	D <sup>2</sup> PAK	(TO-26
	9 -	M	3 = halo	aon_fro		-compl	iant an	d termi	nation l

ORDERING INFORMATION							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-43CTQ080S-M3	50	1000	Antistatic plastic tubes				
VS-43CTQ080STRR-M3	800	800	13" diameter reel				
VS-43CTQ080STRL-M3	800	800	13" diameter reel				
VS-43CTQ080-1-M3	50	1000	Antistatic plastic tubes				
VS-43CTQ100S-M3	50	1000	Antistatic plastic tubes				
VS-43CTQ100STRR-M3	800	800	13" diameter reel				
VS-43CTQ100STRL-M3	800	800	13" diameter reel				
VS-43CTQ100-1-M3	50	1000	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS							
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164					
Dimensions	TO-262AA	www.vishay.com/doc?96165					
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444					
	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?96424					
SPICE model		www.vishay.com/doc?95065					

# **Outline Dimensions**



D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

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SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

1

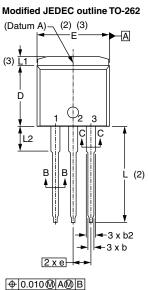


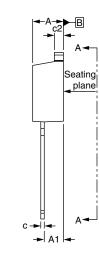
## **Outline Dimensions**

**Vishay Semiconductors** 

**TO-262** 

### **DIMENSIONS** in millimeters and inches

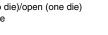


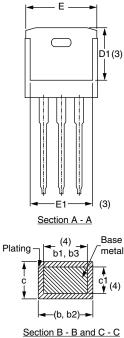


Lead assignments



**Diodes** 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode





Scale: None

CVMDOI	MILLIM	ETERS	INC	NOTEO	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		0 BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

#### Notes

Revision: 04-Oct-10

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

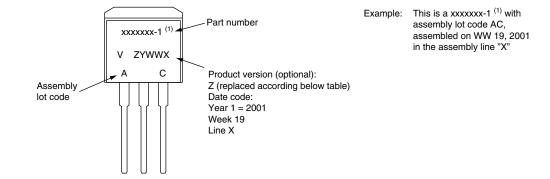
(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

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**TO-262** 



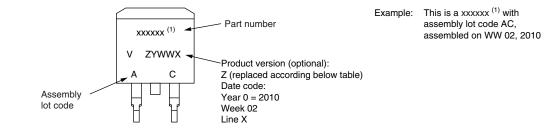
#### Note

<sup>(1)</sup> If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION			
A	Termination lead (Pb)-free			
В	Totally lead (Pb)-free			
E	RoHS-compliant and termination lead (Pb)-free			
F	RoHS-compliant and totally lead (Pb)-free			
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free			
Ν	Halogen-free, RoHS-compliant and totally lead (Pb)-free			
G	Green			



D<sup>2</sup>PAK



#### Note

<sup>(1)</sup> If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
A	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
М	Halogen-free, RoHS-compliant, and termination lead (Pb)-free
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free
G	Green



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